

# **Isc N-Channel MOSFET Transistor**

# STD13NM60N

#### FEATURES

- Drain Current –I<sub>D</sub>= 11A@ T<sub>C</sub>=25°C
- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 600V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)}$  = 360m  $\Omega$  (Max)
- 100% avalanche tested
- · Low input capacitance and gate charge
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



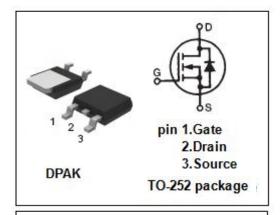
Switching applications

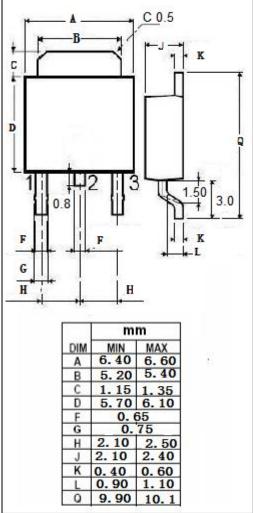
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	V
V <sub>GSS</sub>	Gate-Source Voltage	±25	V
I <sub>D</sub>	Drain Current-Continuous@T <sub>C</sub> =25℃	11	А
I <sub>DM</sub>	Drain Current-Single Pulsed	44	А
P <sub>D</sub>	Total Dissipation	25	W
T <sub>j</sub>	Operating Junction Temperature	Temperature -55~150	
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.39	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =±25V; I <sub>D</sub> =0.25mA	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =5.5A		280	360	mΩ
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V; T <sub>J</sub> =25°C T <sub>J</sub> =125°C			1 100	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =11A, V <sub>GS</sub> = 0 V			1.5	V

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